

Silicon Carbide Diode 4 January 2017

**Product data sheet** 

## 1. General description

Silicon Carbide Schottky diode designed for high frequency switched mode power supplies in a TO252 (DPAK) plastic package.

## 2. Features and benefits

- Highly stable switching performance
- High forward surge capability I<sub>FSM</sub>
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

## 3. Applications

- Power factor correction
- Telecom/Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED/OLED TV
- Motor Drives

## 4. Quick reference data

Table 1. Quid	ck reference data						
Symbol	Parameter	Conditions	N	/lin	Тур	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-		-	650	V
I <sub>F(AV)</sub>	average forward current	$\delta = 0.5$ ; T <sub>mb</sub> $\leq$ 119 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-		-	8	A
Tj	junction temperature		-		-	175	°C
Static chara	octeristics						
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-		1.5	1.7	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-		1.8	2.1	V
Dynamic ch	aracteristics						
Q <sub>r</sub>	recovered charge	$I_F = 8 \text{ A}; \text{ d}I_F/\text{d}t = 500 \text{ A}/\mu\text{s}; \text{ V}_R = 400 \text{ V};$ $T_j = 25 \text{ °C}; \frac{\text{Fig. 7}}{2}$	-		13	-	nC

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# 5. Pinning information

Table 2	. Pinning inf	formation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	n.c.	not connected	mb	K — A 001aaa020
2	K	cathode[1]		001aaa020
3	А	anode		
mb	К	mounting base; connected to cathode		
			DPAK (TO252NS)	

[1] It is not possible to connect to pin 2 of the TO252 package.

# 6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
NXPSC08650D	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	TO252NS				

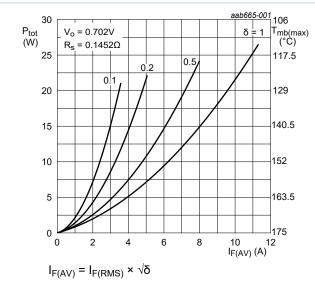
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## 7. Limiting values

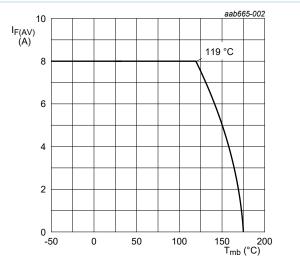
### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>RRM</sub>	repetitive peak reverse voltage		-	650	V
V <sub>RWM</sub>	crest working reverse voltage		-	650	V
V <sub>R</sub>	reverse voltage	DC	-	650	V
I <sub>F(AV)</sub>	average forward current	δ = 0.5; T <sub>mb</sub> ≤ 119 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3; Fig. 4	-	8	A
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 $\ ; t_p$ = 25 $\mu s;$ square-wave pulse	-	16	A
I <sub>FSM</sub>	non-repetitive peak	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	-	48	А
	forward current	t <sub>p</sub> = 10 μs; T <sub>j(init)</sub> = 25 °C; square-wave pulse	-	385	A
T <sub>stg</sub>	storage temperature		-55	175	°C
Tj	junction temperature		-	175	°C





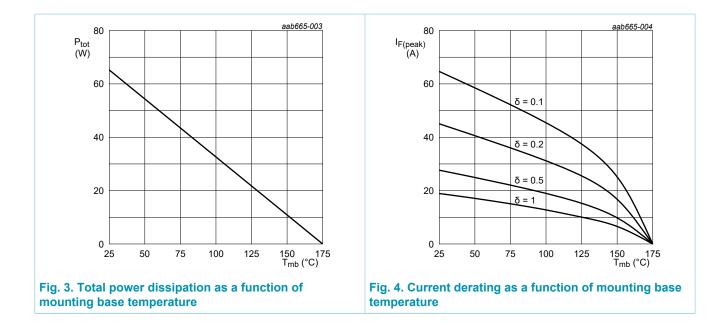




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# NXPSC08650D

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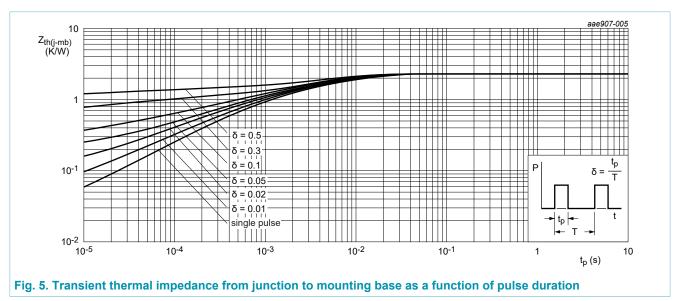


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### 8. Thermal characteristics

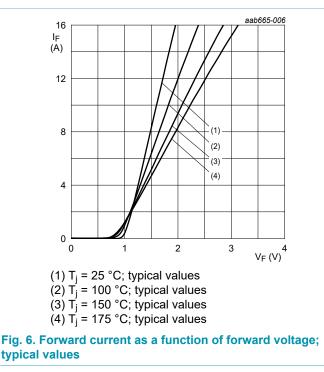
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	<u>Fig. 5</u>	-	-	2.3	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient free air	Device mounted on an FR4 Printed- Circuit Board	-	50	-	K/W

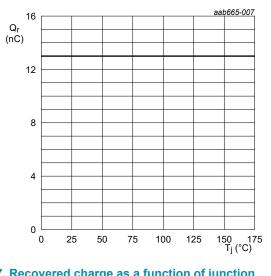


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## 9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		· · · · ·			
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 8 A; T <sub>j</sub> = 25 °C; <u>Fig. 6</u>	-	1.5	1.7	V
		I <sub>F</sub> = 8 A; T <sub>j</sub> = 150 °C; <u>Fig. 6</u>	-	1.8	2.1	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 650 V; T <sub>j</sub> = 25 °C	-	-	230	μA
		V <sub>R</sub> = 650 V; T <sub>j</sub> = 150 °C	-	-	700	μA
Dynamic ch	naracteristics		· · ·			
Q <sub>r</sub>	recovered charge	I <sub>F</sub> = 8 A; dI <sub>F</sub> /dt = 500 A/μs; V <sub>R</sub> = 400 V; T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	13	-	nC
C <sub>d</sub>	diode capacitance	f = 1 MHz; V <sub>R</sub> = 1 V; T <sub>j</sub> = 25 °C	-	260	-	pF
		f = 1 MHz; V <sub>R</sub> = 300 V; T <sub>j</sub> = 25 °C	-	30	-	pF
		f = 1 MHz; V <sub>R</sub> = 600 V; T <sub>i</sub> = 25 °C	-	24	-	pF







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## 10. Package outline

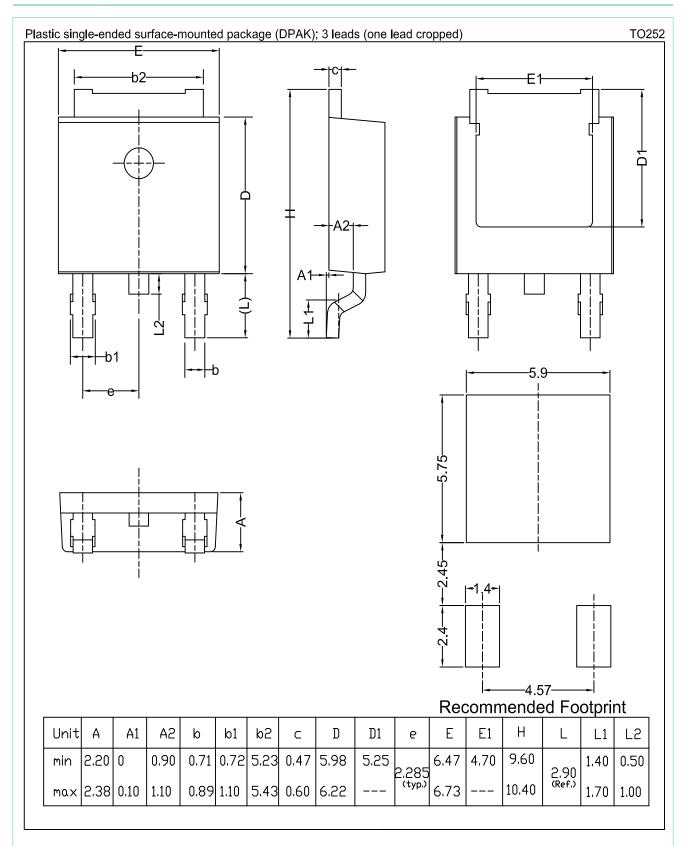


Fig. 8. Package outline DPAK (TO252NS)

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## 11. Legal information

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Document status [1][2]	Product status [ <u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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